



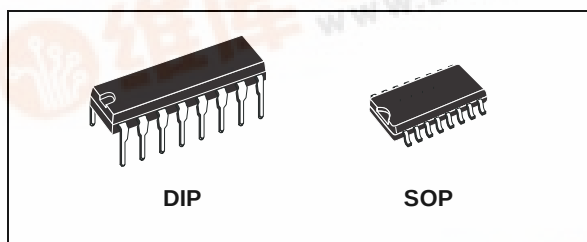
HCF40162B

SYNCHRONOUS PROGRAMMABLE 4-BIT DECADE COUNTER WITH SYNCHRONOUS CLEAR

- INTERNAL LOOK-AHEAD FOR FAST COUNTING
- CARRY OUTPUT FOR CASCADING
- SYNCHRONOUSLY PROGRAMMABLE
- LOW-POWER TTL COMPATIBILITY
- STANDARDIZED SYMMETRICAL OUTPUT CHARACTERISTICS
- QUIESCENT CURRENT SPECIF. UP TO 20V
- 5V, 10V AND 15V PARAMETRIC RATINGS
- INPUT LEAKAGE CURRENT
 $I_l = 100\text{nA}$ (MAX) AT $V_{DD} = 18\text{V}$ $T_A = 25^\circ\text{C}$
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC JESD13B "STANDARD SPECIFICATIONS FOR DESCRIPTION OF B SERIES CMOS DEVICES"

DESCRIPTION

HCF40162B is a monolithic integrated circuit fabricated in Metal Oxide Semiconductor technology available in DIP and SOP packages. HCF40162B is a 4-bit synchronous programmable counter. The CLEAR function is synchronous. A low level at the CLEAR input sets all four outputs low on the next positive CLOCK edge. A low level at the LOAD inputs disables the counter and causes the output to agree with the set-up data after the following CLOCK pulse regardless of the condition of the ENABLE inputs. The carry

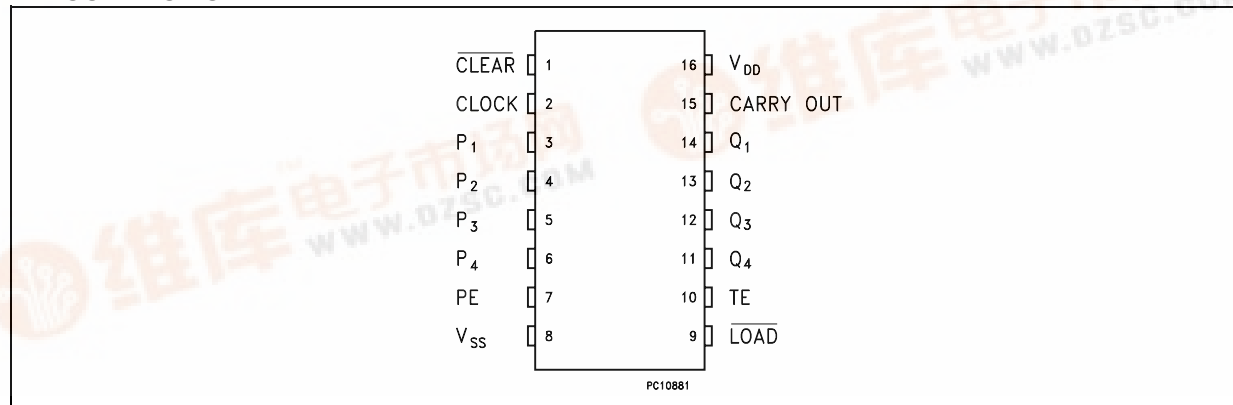


ORDER CODES

PACKAGE	TUBE	T & R
DIP	HCF40162BEY	
SOP	HCF40162BM1	HCF40162M013TR

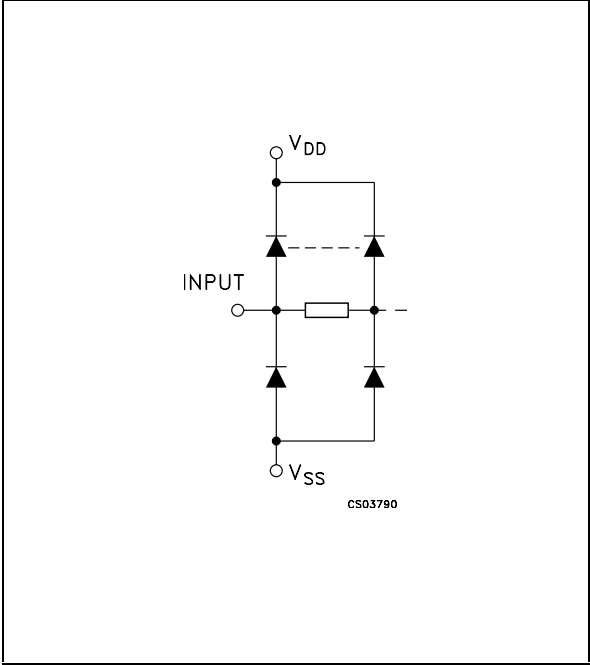
look-ahead circuitry provides for cascading counter for n-bit synchronous application without additional gating. Counting is enabled when both the PE and TE inputs are high. The TE input is fed forward to enable COUT. This enable output produces a positive output pulse with a duration approximately equal to the positive portion of the Q1 output. This positive overflow carry pulse can be used to enable successive cascaded stages. Logic transitions at the PE and TE inputs may occur when the clock is either high or low.

PIN CONNECTION



HCF40162B

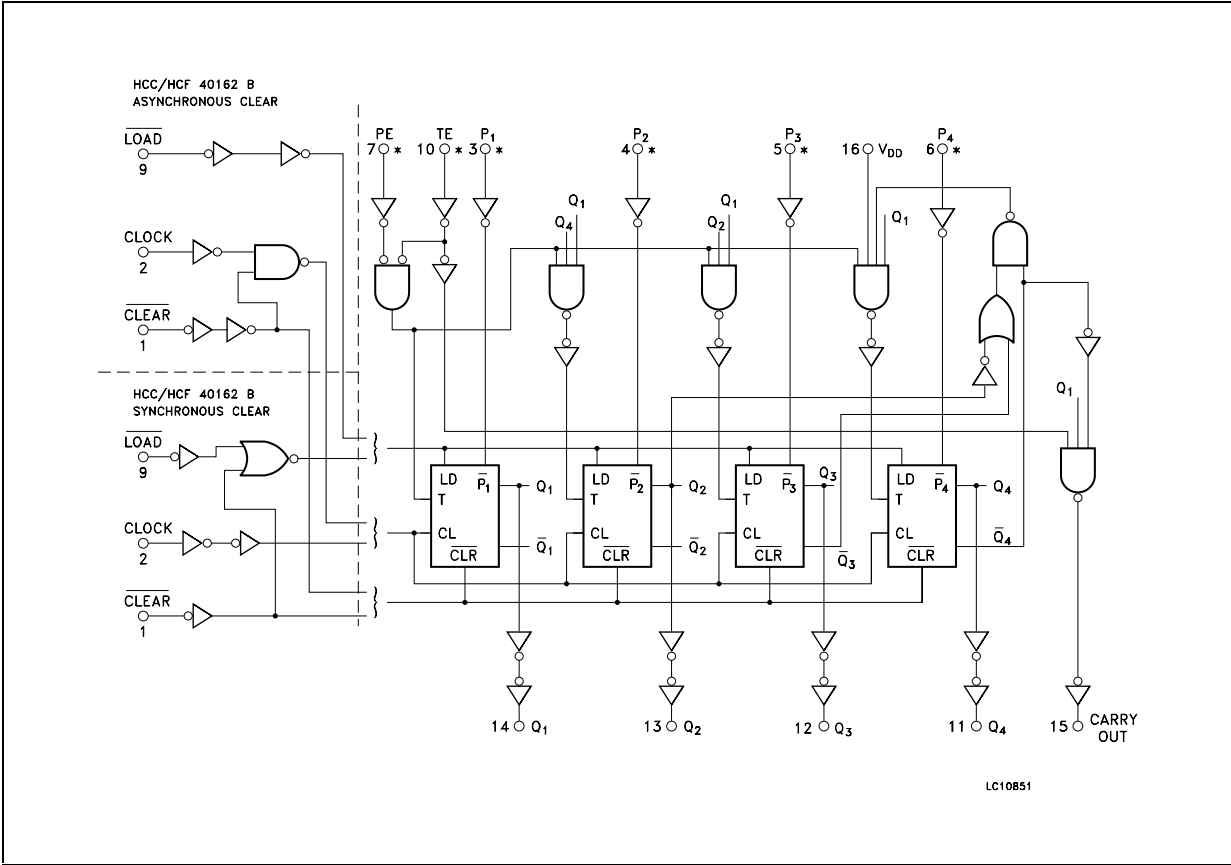
IINPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
1	$\overline{\text{CLEAR}}$	Synchronous Master Reset
2	CLOCK	Clock Input (LOW to HIGH, Edge-triggered)
3, 4, 5, 6	P1 to P4	Data Inputs
7	PE	Count Enable Input
10	TE	Count Enable Carry Input
9	LOAD	Parallel Enable Input
14, 13, 12, 11	Q1 to Q4	Flip Flop Outputs
15	CARRY OUT	Terminal Count Output
8	V_{SS}	Negative Supply Voltage
16	V_{DD}	Positive Supply Voltage

LOGIC DIAGRAM

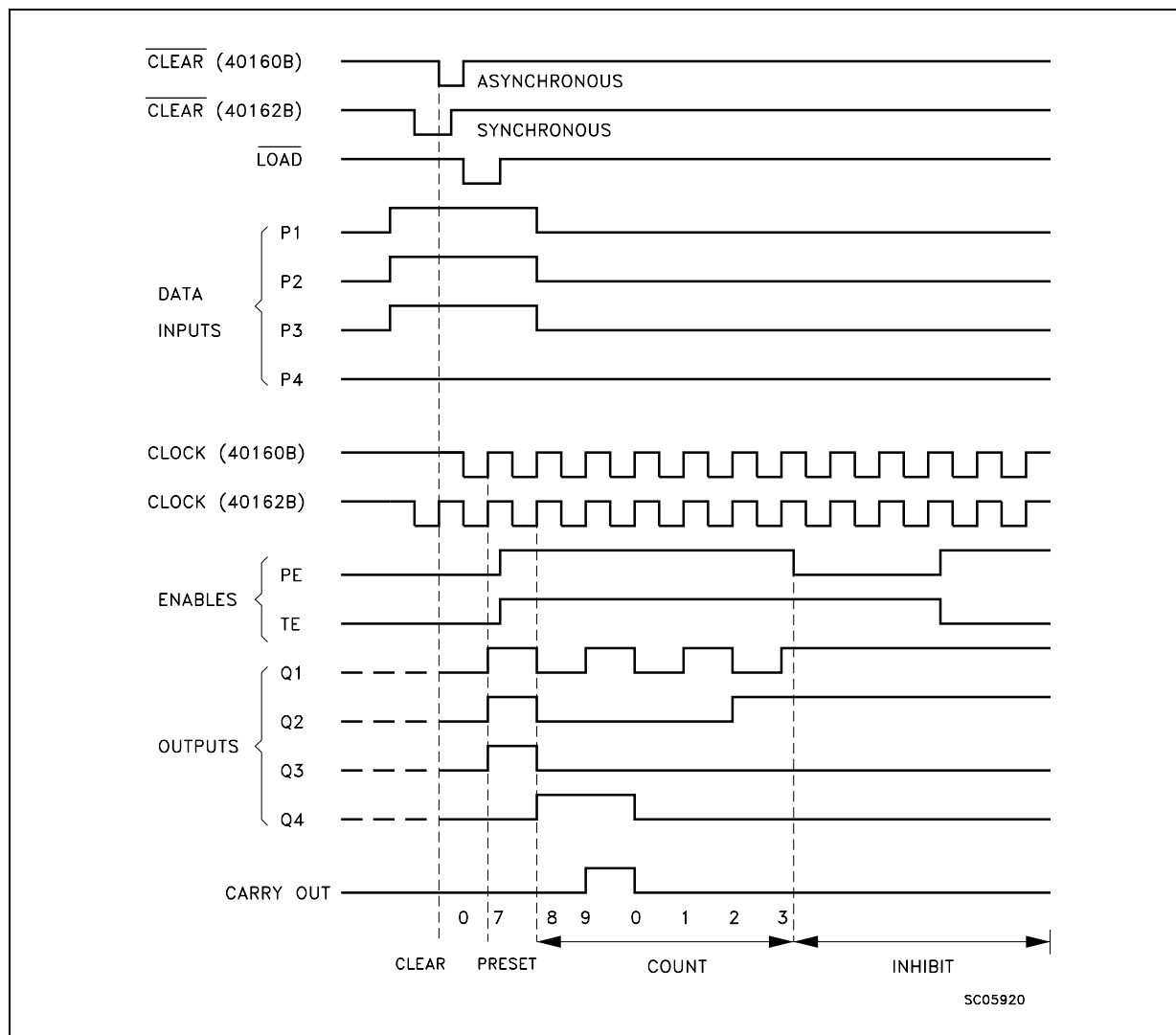


TRUTH TABLE

CLOCK	$\overline{\text{CLR}}$	$\overline{\text{LOAD}}$	PE	TE	OPERATION
	H	L	X	X	PRESET
	H	H	L	X	NC
	H	H	X	L	NC
	H	H	H	H	COUNT
	L	X	X	X	X
	H	X	X	X	X

(X) : Don't Care
NC : No Change

TIMING DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{DD}	Supply Voltage	-0.5 to +22	V
V_I	DC Input Voltage	-0.5 to $V_{DD} + 0.5$	V
I_I	DC Input Current	± 10	mA
P_D	Power Dissipation per Package	200	mW
	Power Dissipation per Output Transistor	100	mW
T_{op}	Operating Temperature	-55 to +125	°C
T_{stg}	Storage Temperature	-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

All voltage values are referred to V_{SS} pin voltage.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{DD}	Supply Voltage	3 to 20	V
V_I	Input Voltage	0 to V_{DD}	V
T_{op}	Operating Temperature	-55 to 125	°C

DC SPECIFICATIONS

Symbol	Parameter	Test Condition				Value							Unit
		V _I (V)	V _O (V)	I _O (μA)	V _{DD} (V)	T _A = 25°C			-40 to 85°C		-55 to 125°C		
						Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
I _L	Quiescent Current	0/5			5		0.04	5		150		150	μA
		0/10			10		0.04	10		300		300	
		0/15			15		0.04	20		600		600	
		0/20			20		0.08	100		3000		3000	
V _{OH}	High Level Output Voltage	0/5		<1	5	4.95			4.95		4.95		V
		0/10		<1	10	9.95			9.95		9.95		
		0/15		<1	15	14.95			14.95		14.95		
V _{OL}	Low Level Output Voltage	5/0		<1	5		0.05			0.05		0.05	V
		10/0		<1	10		0.05			0.05		0.05	
		15/0		<1	15		0.05			0.05		0.05	
V _{IH}	High Level Input Voltage		0.5/4.5	<1	5	3.5			3.5		3.5		V
			1/9	<1	10	7			7		7		
			1.5/13.5	<1	15	11			11		11		
V _{IL}	Low Level Input Voltage		4.5/0.5	<1	5			1.5		1.5		1.5	V
			9/1	<1	10			3		3		3	
			13.5/1.5	<1	15			4		4		4	
I _{OH}	Output Drive Current	0/5	2.5	<1	5	-1.36	-3.2		-1.1		-1.1		mA
		0/5	4.6	<1	5	-0.44	-1		-0.36		-0.36		
		0/10	9.5	<1	10	-1.1	-2.6		-0.9		-0.9		
		0/15	13.5	<1	15	-3.0	-6.8		-2.4		-2.4		
I _{OL}	Output Sink Current	0/5	0.4	<1	5	0.44	1		0.36		0.36		mA
		0/10	0.5	<1	10	1.1	2.6		0.9		0.9		
		0/15	1.5	<1	15	3.0	6.8		2.4		2.4		
I _I	Input Leakage Current	0/18	Any Input		18		±10 ⁻⁵	±0.1		±1		±1	μA
C _I	Input Capacitance		Any Input				5	7.5					pF

The Noise Margin for both "1" and "0" level is: 1V min. with V_{DD}=5V, 2V min. with V_{DD}=10V, 2.5V min. with V_{DD}=15V

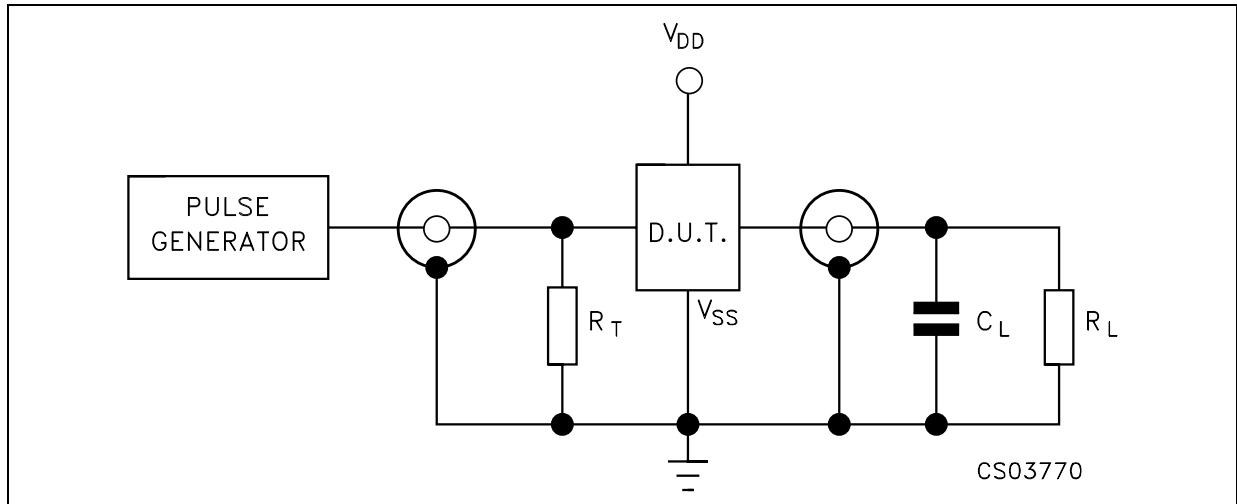
HCF40162B

DYNAMIC ELECTRICAL CHARACTERISTICS ($T_{amb} = 25^{\circ}\text{C}$, $C_L = 50\text{pF}$, $R_L = 200\text{K}\Omega$, $t_r = t_f = 20\text{ ns}$)

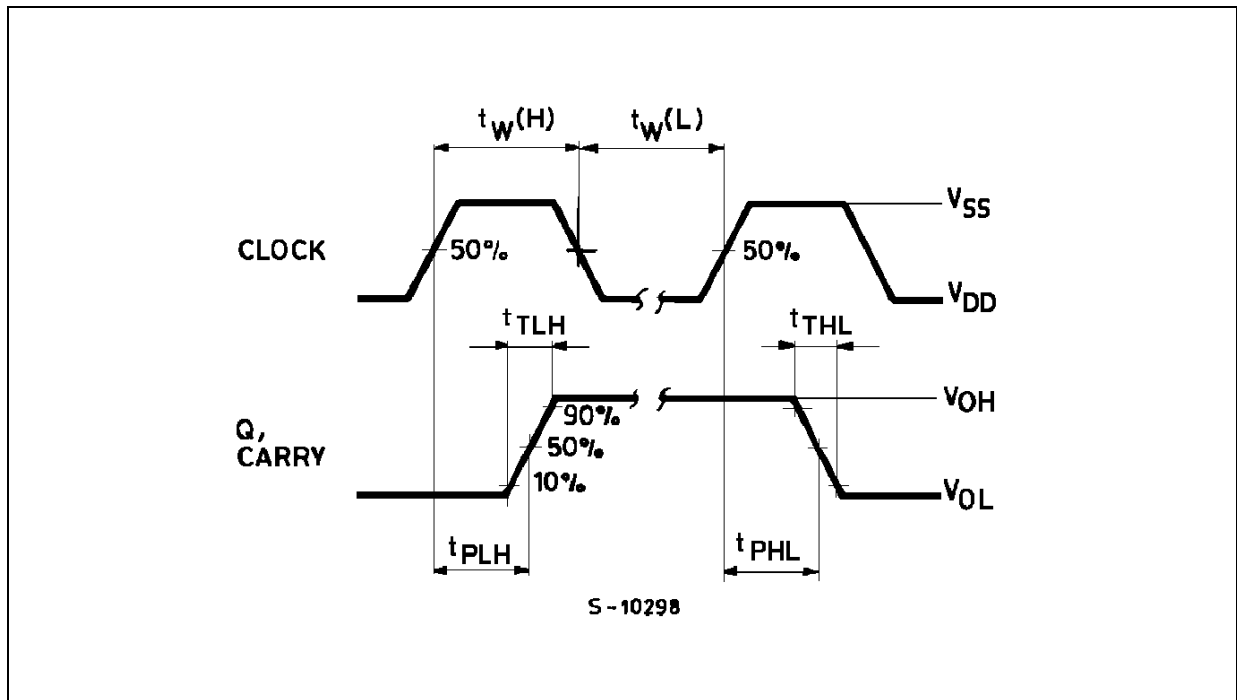
Symbol	Parameter	Test Condition		Value (*)			Unit
		V_{DD} (V)		Min.	Typ.	Max.	
t_{PLH} t_{PHL}	Propagation Delay Time Clock to Q	5			200	400	ns
		10			80	160	
		15			60	120	
t_{PLH} t_{PHL}	Propagation Delay Time Clock to C_{OUT}	5			225	450	ns
		10			95	190	
		15			70	140	
t_{PLH} t_{PHL}	Propagation Delay Time TE to C_{OUT}	5			125	250	ns
		10			55	110	
		15			40	80	
t_{setup}	Setup Time Data to Clock	5		240	120		ns
		10		90	45		
		15		60	30		
t_{setup}	Setup Time Load to Clock	5		240	120		ns
		10		90	45		
		15		60	30		
t_{setup}	Setup Time PE or TE to Clock	5		340	170		ns
		10		140	70		
		15		100	50		
t_{hold}	Hold Time	5		0			ns
		10		0			
		15		0			
t_{THL} t_{TLH}	Transition Time	5			100	200	ns
		10			50	100	
		15			40	80	
t_W	Clock Input Pulse Width	5		170	85		ns
		10		70	35		
		15		50	25		
f_{CL}	Maximum Clock Input Frequency	5		2	3		MHz
		10		5.5	8.5		
		15		8	12		
t_r t_f	Clock Input Rise or Fall Time	5				200	ns
		10				70	
		15				15	
t_{SETUP}	Propagation Delay Time Clear to Clock	5		340	170		ns
		10		140	70		
		15		100	50		
t_{hold}	Hold Time Clear to Clock	5		0			ns
		10		0			
		15		0			
t_{rem}	Clear Removal Time	5		200	100		ns
		10		100	50		
		15		70	35		

(*) Typical temperature coefficient for all V_{DD} value is 0.3 %/°C.

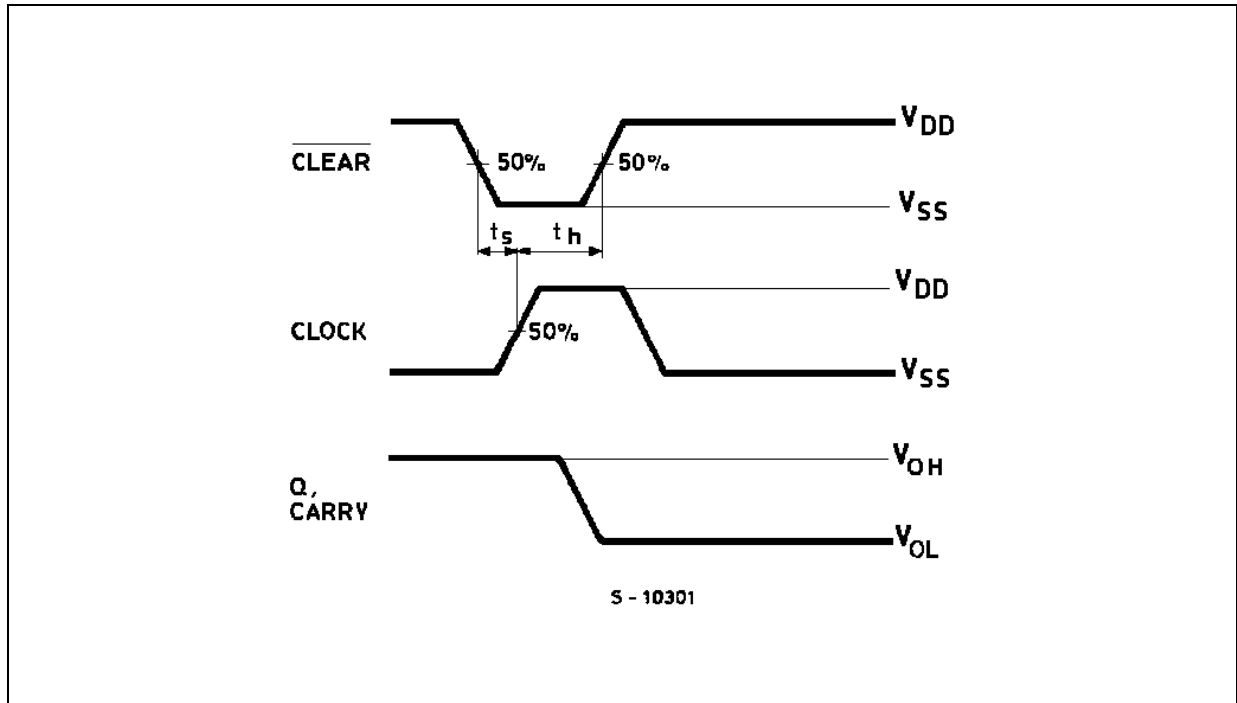
TEST CIRCUIT



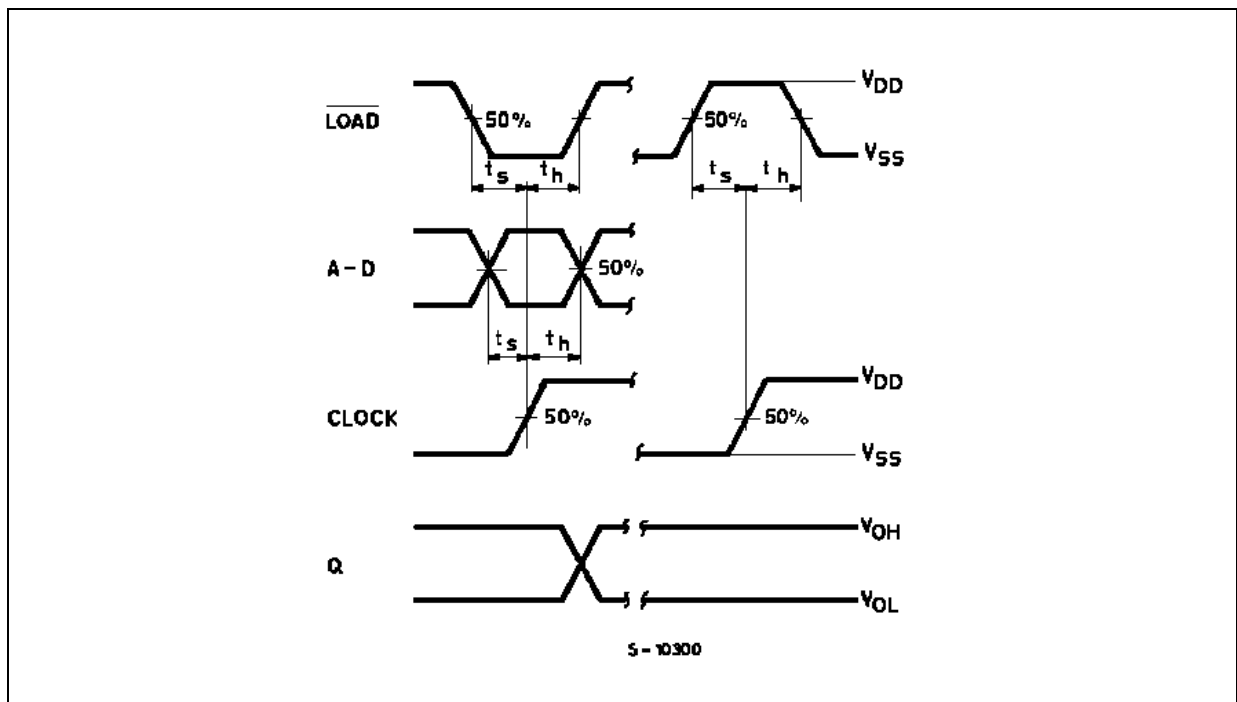
$C_L = 50\text{pF}$ or equivalent (includes jig and probe capacitance)
 $R_L = 200\text{K}\Omega$
 $R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

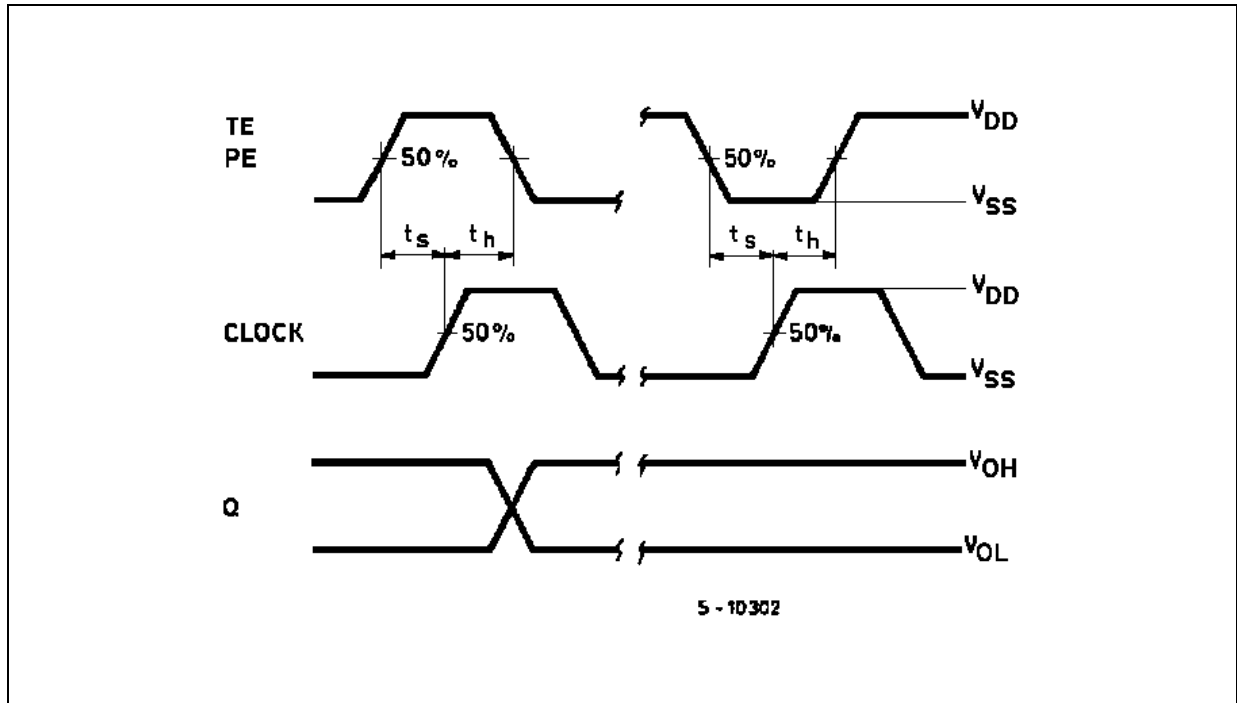
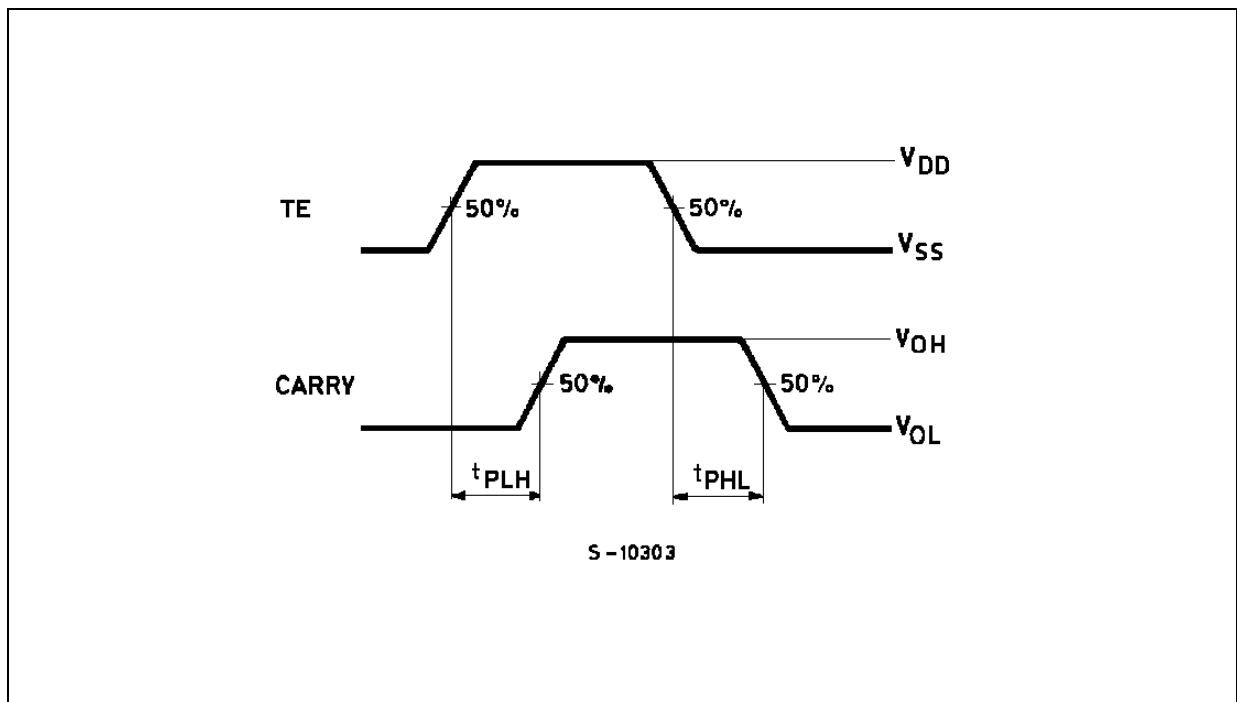
WAVEFORM 1 : PROPAGATION DELAY TIMES, MINIMUM PULSE WIDTH ($f=1\text{MHz}$; 50% duty cycle)

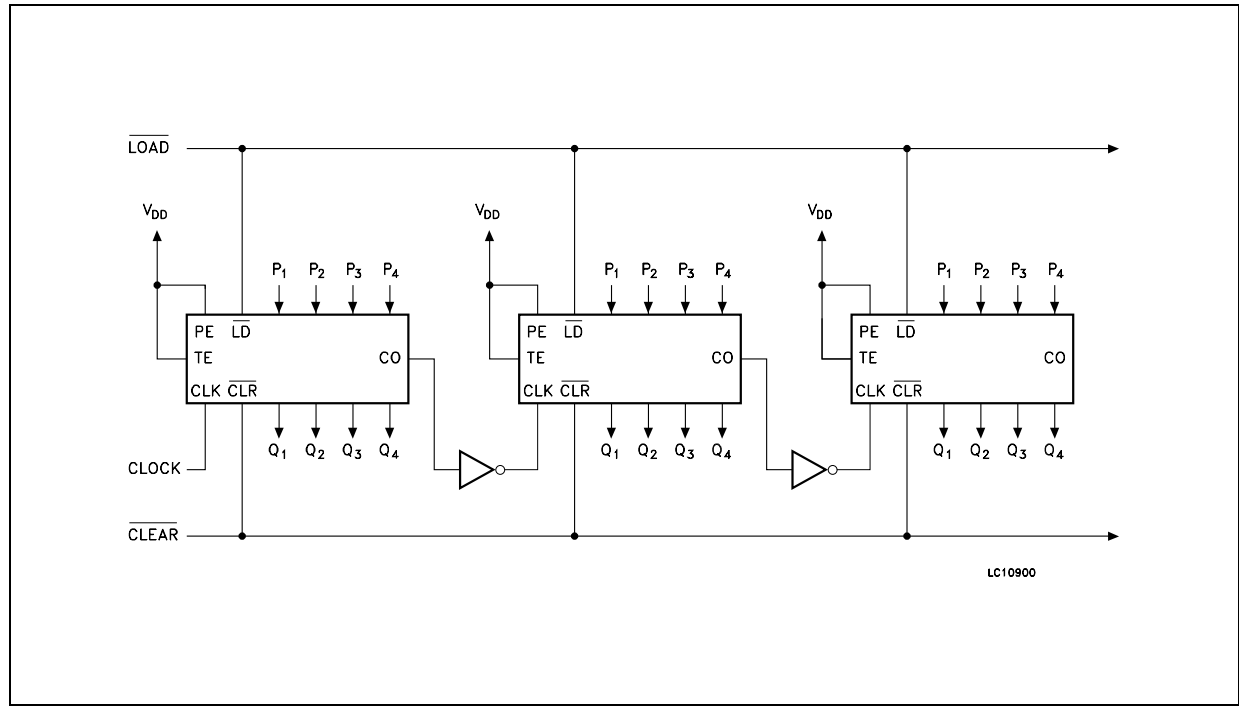
WAVEFORM 2 : MINIMUM SETUP AND HOLD TIME ($f=1\text{MHz}$; 50% duty cycle)



WAVEFORM 3 : MINIMUM SETUP AND HOLD TIME ($f=1\text{MHz}$; 50% duty cycle)

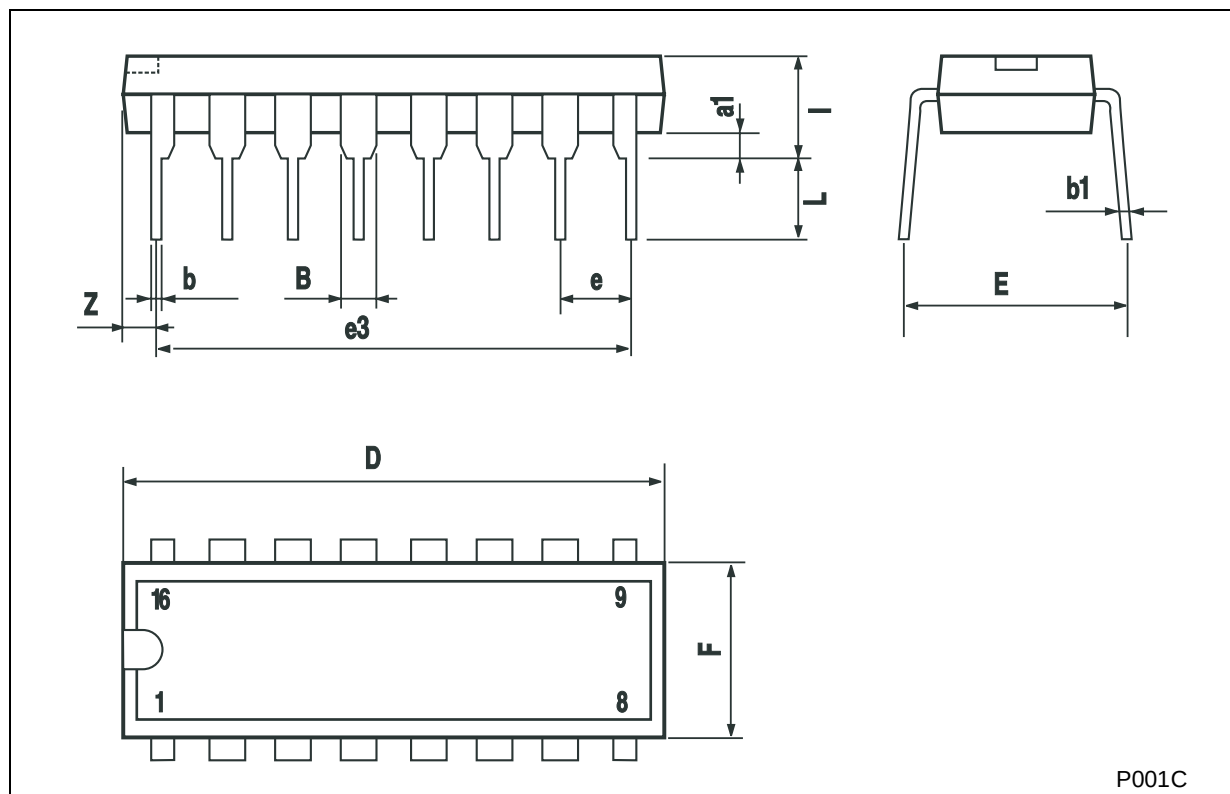


WAVEFORM 4 : MINIMUM SETUP AND HOLD TIME ($f=1\text{MHz}$; 50% duty cycle)**WAVEFORM 5 : PROPAGATION DELAY TIME** ($f=1\text{MHz}$; 50% duty cycle)

TYPICAL APPLICATION: CASCADING COUNTER PACKAGES IN THE RIPPLE-CLOCKED MODE

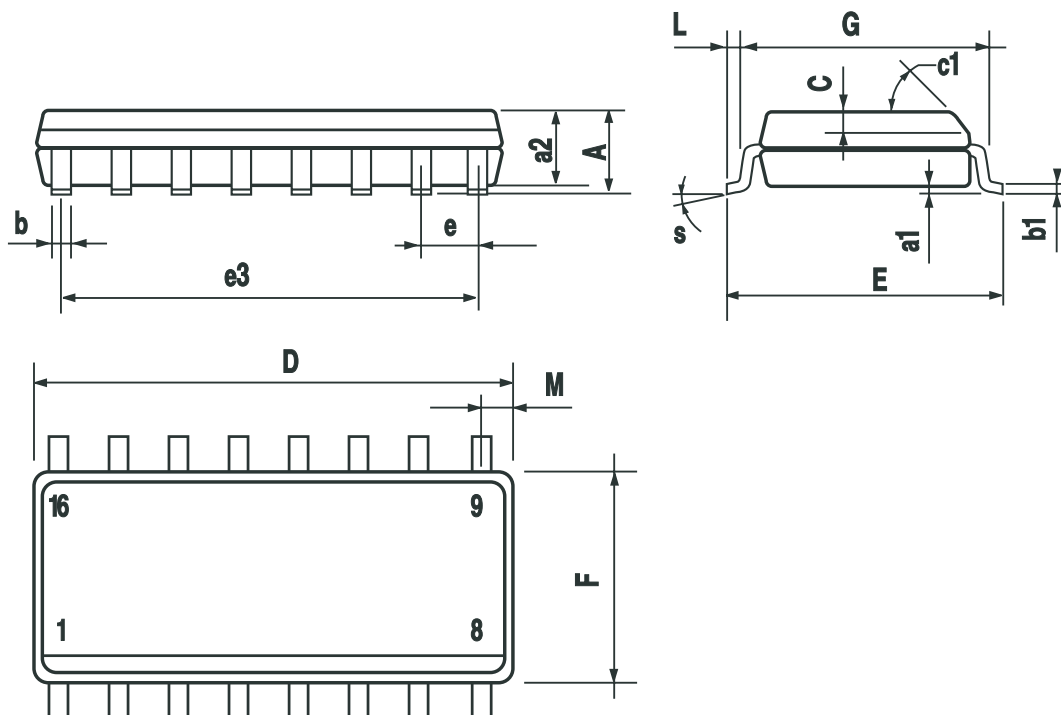
Plastic DIP-16 (0.25) MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050



SO-16 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	9.8		10	0.385		0.393
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.62			0.024
S	8° (max.)					



PO13H

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

© The ST logo is a registered trademark of STMicroelectronics

© 2002 STMicroelectronics - Printed in Italy - All Rights Reserved
STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco
Singapore - Spain - Sweden - Switzerland - United Kingdom - United States.

© <http://www.st.com>